



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re patent application of

Toshiya Uemura

Serial No.: 10/694,760

Group Art Unit: Not Yet Assigned

Filing Date: October 29, 2003

Examiner: Unknown

For: III GROUP NITRIDE SYSTEM COMPOUND SEMICONDUCTOR LIGHT
EMITTING ELEMENT AND METHOD OF MAKING SAME

Honorable Commissioner of Patents
Alexandria, Virginia 22313-1450

INFORMATION DISCLOSURE STATEMENT

Sir:

Under the provisions of 37 CFR §1.97 through §1.99 and pursuant to applicant's duty of disclosure under 37 CFR §1.56, applicant respectfully brings the following documents listed on the attached form PTO-1449, to the attention of the Examiner in charge of the above-identified application. Copies of the listed documents are provided herewith for the convenience of the Examiner. In compliance with the concise explanation requirement under 37 CFR §1.98(a)(3), the relevance of these documents is discussed on pages 2 and 3 of the subject application. Further, English-language Abstracts is attached to one of the references.

This citation does not constitute an admission that the references are relevant or material to the claims. They are only cited as constituting related art of which the applicant is aware.

It is respectfully requested that the listed references be considered by the Examiner and formally made of record in this application.

Please charge any deficiencies in fees and credit any overpayment of fees to Attorney's Deposit Account No. 50-0481.

Respectfully submitted,

Sean M. McGinn
Registration No. 34,386

Date: 1/23/04

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INFORMATION DISCLOSURE CITATION

(Use several sheets if necessary)

JAN 23 2004



Docket Number (Optional)

PTGF-03068

Application Number

10/694,760

Applicant(s)

Toshiya Uemura

Filing Date

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U.S. PATENT DOCUMENTS

*EXAMINER INITIAL	REF	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE

FOREIGN PATENT DOCUMENTS

REF	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	Translation	
						YES	NO
	2001-267242	09/28/2001	Japan			✓	

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)

Kazuyuki Tadatomo, et al., "High Output Power InGaN Ultraviolet Light-Emitting Diodes Fabricated on Patterned Substrates Using Metalorganic Vapor Phase Epitaxy", Japanese Journal Appl. Phys. Vol 40., Part 2, No. 6B, June 15, 2001, pp. L583-585.

EXAMINER	DATE CONSIDERED
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EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP Section 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.